

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

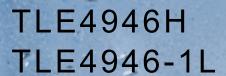
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

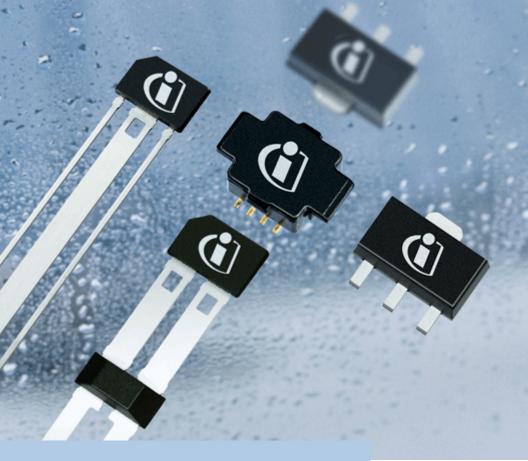








High Precision Bipolar Hall-Effect Latch



Sensors



Edition 2005-10
Published by Infineon Technologies AG, St.-Martin-Strasse 53, 81669 München, Germany
© Infineon Technologies AG 2005.
All Rights Reserved.

#### Attention please!

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

#### Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

#### Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

TLE4946H TLE4946-1L

Revision History: 2005-10 V 1.1

Previous Version: 1.0

Page	Subjects (major changes since last revision)
6	Figure 1 Correction of dimensions for package PG-SSO-3-2
14	Figure 6 Correction of dimensions
16	Figure 10 Correction of dimensions
11	Table 7 New entry: Magnetic Offset for TLE4946-1L

### We Listen to Your Comments

Any information within this document that you feel is wrong, unclear or missing at all? Your feedback will help us to continuously improve the quality of this document. Please send your proposal (including a reference to this document) to: feedback.sensors@infineon.com

# TLE4946H TLE4946-1L



1	Overview
1.1	Features
1.2	Functional Description
1.3	Pin Configuration (top view)
2	General
2.1	Block Diagram
2.2	Circuit Description
3	Maximum Ratings 8
4	Operating Range
5	Electrical and Magnetic Parameters       10         Field Direction Definion       12
6	Timing Diagram
7	Package Information
7.1	Package Marking
7.2	Distance between Chip and Package Surface
7.3	Package Outlines
	PCB Footprint for SC59



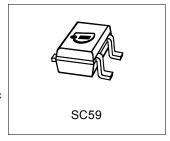
# **High Precision Bipolar Hall-Effect Latch**

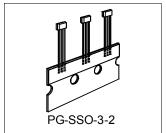
TLE4946H TLE4946-1L

### 1 Overview

#### 1.1 Features

- 2.7 V to 24 V supply voltage operation
- Operation from unregulated power supply
- High sensitivity and high stability of the magnetic switching points
- High resistance to mechanical stress by Active Error Compensation
- Reverse battery protection (– 18 V)
- Superior temperature stability
- Peak temperatures up to 195°C without damage
- Low jitter (typ. 1 µs)
- High ESD performance (± 6 kV HBM)
- Digital output signal
- SMD package SC59 (SOT23 compatible) -(TLE4946H))
- Leaded package PG-SSO-3-2 (TLE4946-1L)





# 1.2 Functional Description

The TLE4946H and the TLE4946-1L are integrated circuit Hall-effect sensors designed specifically for highly accurate applications.

Precise magnetic switching points and high temperature stability are achieved by active compensation circuits and chopper techniques on chip.

Туре	Package
TLE4946H	SC59
TLE4946-1L	PG-SSO-3-2



Overview

# **1.3 Pin Configuration** (top view)

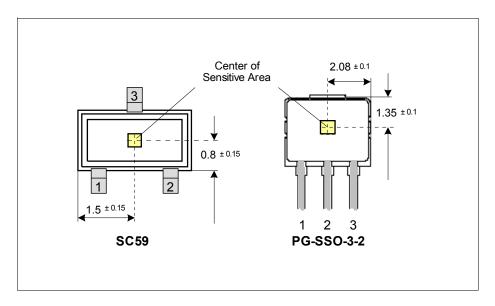


Figure 1 Pin Definition and Center of Sensitive Area

Table 1 Pin Definitions and Functions SC59

Pin No.	Symbol	Function
1	$V_{S}$	Supply voltage
2	Q	Output
3	GND	Ground

Table 2 Pin Definitions and Functions PG-SSO-3-2

Pin No.	Symbol	Function
1	$V_{S}$	Supply voltage
2	GND	Ground
3	Q	Output



General

### 2 General

### 2.1 Block Diagram

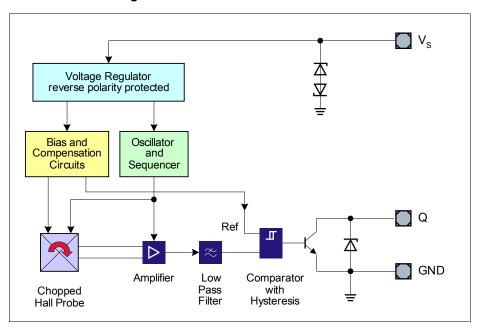


Figure 2 Block Diagram

# 2.2 Circuit Description

The chopped Hall IC Switch comprises a Hall probe, bias generator, compensation circuits, oscillator, and output transistor.

The bias generator provides currents for the Hall probe and the active circuits. Compensation circuits stabilize the temperature behavior and reduce technology variations.

The Active Error Compensation rejects offsets in signal stages and the influence of mechanical stress to the Hall probe caused by molding and soldering processes and other thermal stresses in the package.

This chopper technique together with the threshold generator and the comparator ensure high accurate magnetic switching points.



# **Maximum Ratings**

# 3 Maximum Ratings

Table 3 Absolute Maximum Ratings  $T_i = -40^{\circ}\text{C to } 150^{\circ}\text{C}$ 

Parameter	Symbol	Limit '	Values	Unit	Conditions	
		min.	max.			
Supply voltage	$V_{S}$	- 18 - 18 - 18	18 24 26	V	for 1 h, $R_{\rm s} \ge 200~\Omega$ for 5 min, $R_{\rm s} \ge 200~\Omega$	
Supply current through protection device	$I_{\mathbb{S}}$	- 50	+ 50	mA		
Output voltage	$V_{Q}$	- 0.7 - 0.7	18 26	V	for 5 min @ 1.2 kΩ pull up	
Continuous output current	$I_{Q}$	- 50	+ 50	mA		
Junction temperature	$T_{j}$	- - -	155 165 175 195	°C	for 2000 h (not additive) for 1000 h (not additive) for 168 h (not additive) for 3 x 1 h (additive)	
Storage temperature	$T_{\mathbb{S}}$	- 40	150	°C		
Magnetic flux density	В	_	unlimited	mT		

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4 ESD Protection 1)

Parameter	Symbol	Lim	nit Values	Unit	Notes	
		min.	max.			
ESD voltage	$V_{ESD}$	_	± 6	kV	HBM, $R = 1.5 \text{ k}\Omega$ , C = 100  pF $T_A = 25^{\circ}\text{C}$	

Human Body Model (HBM) tests according to: EOS/ESD Association Standard S5.1-1993 and Mil. Std. 883D method 3015.7



# **Operating Range**

# 4 Operating Range

# Table 5 Operating Range

Parameter	Symbol	Limit Values			Unit	Conditions	
		min.	typ.	max.			
Supply voltage	$V_{S}$	2.7	-	18	V		
Output voltage	$V_{Q}$	- 0.7	_	18	V		
Junction temperature	$T_{\rm j}$	- 40	-	150	°C		
Output current	$I_{Q}$	0	-	20	mA		



#### **Electrical and Magnetic Parameters**

# 5 Electrical and Magnetic Parameters

Table 6 Electrical Characteristics 1).

Parameter	Symbol	Limit Values			Unit	Conditions	
		min. typ. m		max.			
Supply current	$I_{S}$	2	4	6	mA	V <sub>S</sub> = 2.7 V 18 V	
Reverse current	$I_{SR}$	0	0.2	1	mA	V <sub>S</sub> = – 18 V	
Output saturation voltage	$V_{QSAT}$	_	0.3	0.6	V	I <sub>Q</sub> = 20 mA	
Output leakage current	$I_{QLEAK}$	_	0.05	10	μΑ	for $V_{\rm Q}$ = 18 V	
Output fall time	$t_{f}$	_	0.02	1	μs	$R_{\rm L}$ = 1.2 k $\Omega$ ; $C_{\rm L}$ = 50 pF	
Output rise time	$t_{r}$	_	0.4	1	μs	see: Figure 3 "Timing Definition" on Page 12	
Chopper frequency	$f_{\sf OSC}$	-	320	_	kHz		
Switching frequency	$f_{\sf SW}$	0	_	15 <sup>2)</sup>	kHz		
Delay time 3)	$t_{\sf d}$	_	13	_	μs		
Output jitter 4)	$t_{\rm QJ}$	_	1	-	μs <sub>RMS</sub>	Typical value for square wave signal 1 kHz	
Power-on time 5)	$t_{PON}$	_	13	-	μs	$V_{\rm S} \ge 2.7 \ { m V}$	
Thermal resistance	$R_{thJA}$	_	100	_	K/W	SC59	
6)		-	_	190		PG-SSO-3-2	

- 1) over operating range, unless otherwise specified. Typical values correspond to  $V_{\rm S}$  =12 V and  $T_{\rm A}$  = 25°C
- 2) To operate the sensor at the max. switching frequency, the value of the magnetic signal amplitude must be 1.4 times higher than for static fields. This is due to the - 3 dB corner frequency of the low pass filter in the signal path.
- 3) Systematic delay between magnetic threshold reached and output switching
- 4) Jitter is the unpredictable deviation of the output switching delay
- 5) Time from applying  $V_S \ge 2.7 \text{ V}$  to the sensor until the output state is valid
- 6) Thermal resistance from junction to ambient

# Calculation of the ambient temperature (SC59 example)

e.g. for  $V_{\rm S}$  = 12.0 V,  $I_{\rm Styp}$  = 4 mA,  $V_{\rm QSATtyp}$  = 0.3 V and  $I_{\rm Q}$  = 20 mA : Power Dissipation:  $P_{\rm DIS}$  = 54.0 mW. In  $T_{\rm A}$  =  $T_{\rm j}$  – ( $R_{\rm th,JA}$   $\times$   $P_{\rm DIS}$ ) = 175°C – (100 K / W  $\times$  0.054 W) Resulting max. ambient temperature:  $T_{\rm A}$  = 169.6°C



# **Electrical and Magnetic Parameters**

Table 7 Magnetic Characteristics TLE4946H 1)

Parameter	Symbol	$T_{j}$ [°C]	Li	mit Valu	ies	Unit	Notes
			min.	typ.	max.		
Operate point	$B_{OP}$	- 40 25 150	11.8 11.0 6.1	15.8 14.0 9.6	19.2 17.0 13.7	mT	TLE4946H
		- 40 25 150	11.3 11.0 10.5	15.4 15.0 14.3	19.5 19.0 18.1		TLE4946-1L
Release point	$B_{RP}$	- 40 25 150	- 19.2 - 17.0 - 13.7	- 15.8 - 14.0 - 9.6	- 11.8 - 11.0 - 6.1	mT	TLE4946H
		- 40 25 150	- 19.5 - 19.0 - 18.1	- 15.4 - 15.0 - 14.3	- 11.3 - 11.0 - 10.5		TLE4946-1L
Hysteresis	$B_{HYS}$	- 40 25 150	- 22.0 -	- 28.0 -	- 34.0 -	mT	TLE4946H
		- 40 25 150	- 22.0 -	- 30.0 -	- 38.0 -		TLE4946-1L
Magnetic Offset	Offset $B_{OFF}$	- 40 25 150	- - 3.0 -	_ _ _	- 3.0 -	mT	TLE4946H <sub>2)</sub>
		- 40 25 150	- -2.0 -	_ _ _	- 2.0 -		TLE4946-1L
Temperature	TC	_	_	- 2000	_	ppm/°C	TLE4946H
compensation of magn. thresholds		-	-	- 350	-		TLE4946-1L
Repeatability of magnetic thresholds 3)	$B_{REP}$		_	20	_	μT <sub>RMS</sub>	Typ. value for $\Delta B / \Delta t$ > 12 mT/ms

<sup>1)</sup> over operating range, unless otherwise specified. Typical values correspond to  $V_{\rm S}$  = 12 V.

Note: Typical characteristics specify mean values expected over the production spread.

<sup>2)</sup>  $B_{OFF} = (B_{OP} + B_{RP}) / 2$ 

<sup>3)</sup>  $B_{\rm REP}$  is equivalent to the noise constant



# **Timing Diagram**

#### **Field Direction Definion**

Positive magnetic fields related with south pole of magnet to the branded side of package.

# 6 Timing Diagram

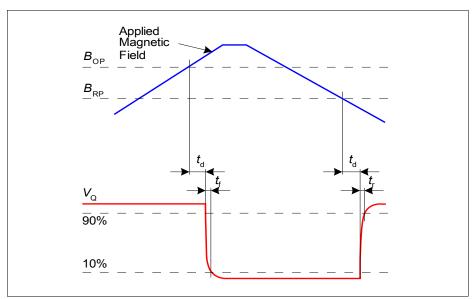


Figure 3 Timing Definition



# 7 Package Information

# 7.1 Package Marking

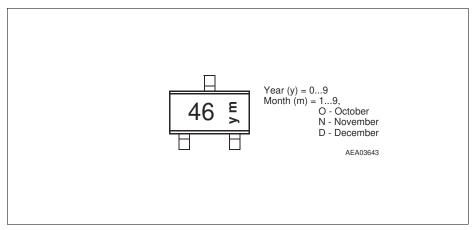


Figure 4 Marking TLE4946H

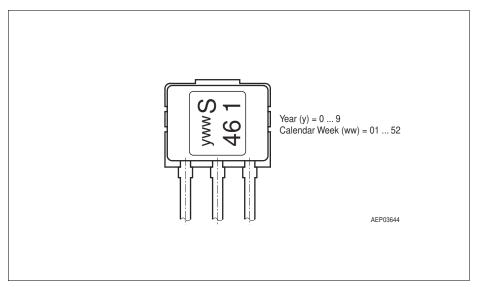


Figure 5 Marking TLE4946-1L



# 7.2 Distance between Chip and Package Surface

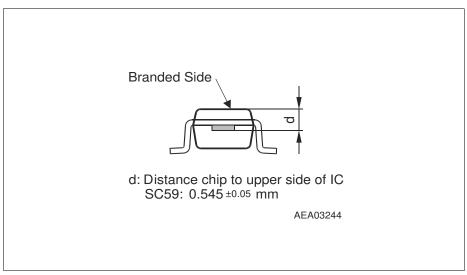


Figure 6 Distance Chip SC59 to Upper Side of IC

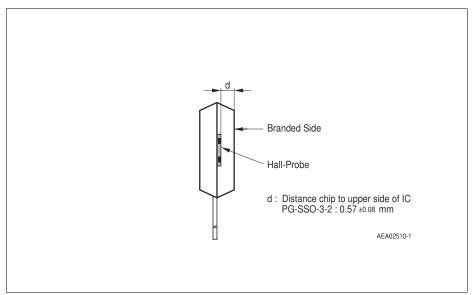


Figure 7 Distance Chip PG-SSO-3-2 to Upper Side of IC



# 7.3 Package Outlines

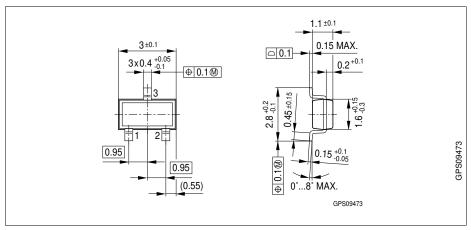


Figure 8 SC59

# **PCB Footprint for SC59**

The following picture shows a recommendation for the PCB layout.

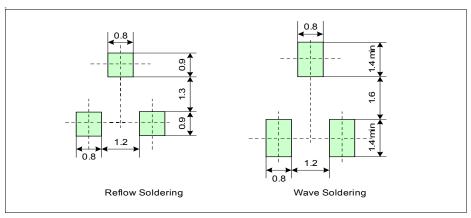


Figure 9 Footprint SC59 (SOT23 compatible)



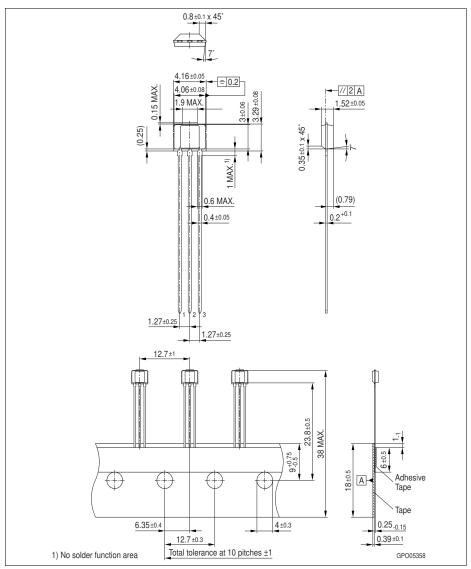


Figure 10 PG-SSO-3-2

Note: You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.

Dimensions in mm



Notes



Notes



Notes

www.infineon.com

Published by Infineon Technologies AG